

Avionics Pulsed Power Transistor 350W, 960-1215 MHz, 10µs Pulse, 10% Duty M/A-COM Products Released, 30 May 07

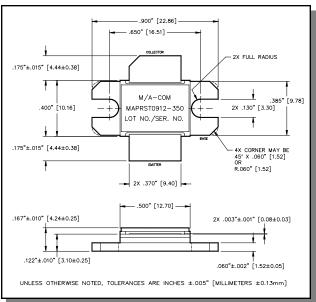
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- · High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS Compliant

## Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	65	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	Ic	32.5	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	1.34	kW
Storage Temperature	$T_{STG}$	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

#### **Outline Drawing**



## Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient )

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA		$BV_CES$	65	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 50V		I <sub>CES</sub>	-	15	mA
Thermal Resistance	Vcc = 50V, Pin = 40W	F = 960, 1090, 1215 MHz	R <sub>TH(JC)</sub>	-	0.13	°C/W
Output Power	Vcc = 50V, Pin = 40W	F = 960, 1090, 1215 MHz	Po	350	-	W
Power Gain	Vcc = 50V, Pin = 40W	F = 960, 1090, 1215 MHz	$G_{P}$	9.4	-	dB
Collector Efficiency	Vcc = 50V, Pin = 40W	F = 960, 1090, 1215 MHz	ης	45	1	%
Input Return Loss	Vcc = 50V, Pin = 40W	F = 960, 1090, 1215 MHz	RL	-	-9	dB
Load Mismatch Stability	Vcc = 50V, Pin = 40W	F = 960 MHz	VSWR-T	-	10:1	-
Load Mismatch Tolerance	Vcc = 50V, Pin = 40W	F = 960, 1090, 1215 MHz	VSWR-S	-	1.5:1	-

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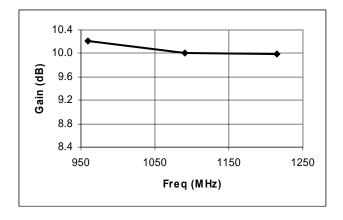
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### **Typical RF Performance**

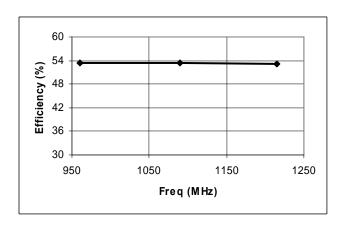
Freq.	Pin	Pout	Gain	∆Gain	lc	Eff	RL	VSWR-S	VSWR-T	P1dB Overdrive	
(MHz)	(W)	(W)	(dB)	(dB)	(A)	(%)	(dB)	(1.5:1)	(10:1)	Pout	Δ Ρο
960	40	421	10.22	ı	15.7	53.4	-19.9	S	Р	496	0.72
1090	40	401	10.01		15.0	53.4	-18.5	S		469	0.69
1215	40	399	9.99	0.23	15.0	53.2	-21.5	S	-	421	0.22

Note:  $\Delta$ **Po(dB)** is the difference between Pout at 1dB overdrive and Pout at Pin = 40W.

#### Gain vs. Frequency



### Collector Efficiency vs. Frequency



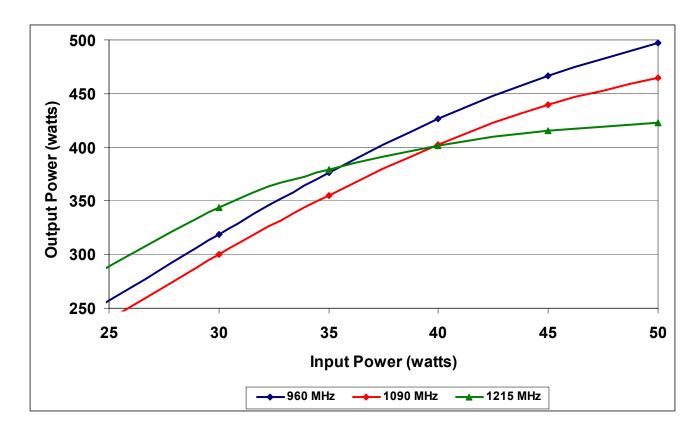
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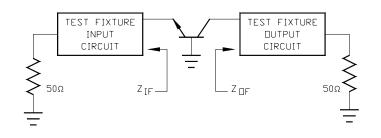
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# RF Power Transfer Curve (Output Power Vs. Input Power)



#### **Broadband Test Fixture Impedance**

F (MHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)		
960	1.8 - j1.7	1.7 - j1.7		
1030	1.7 - j1.4	1.8 - j1.2		
1090	1.6 - j1.2	1.9 - j0.8		
1150	1.4 - j1.0	1.9 - j0.6		
1215	1.2 - j0.8	2.0 - j0.2		



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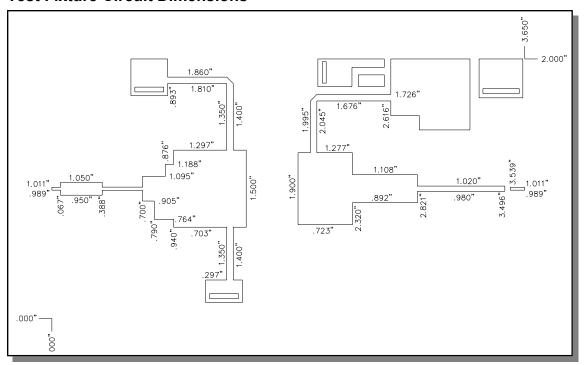
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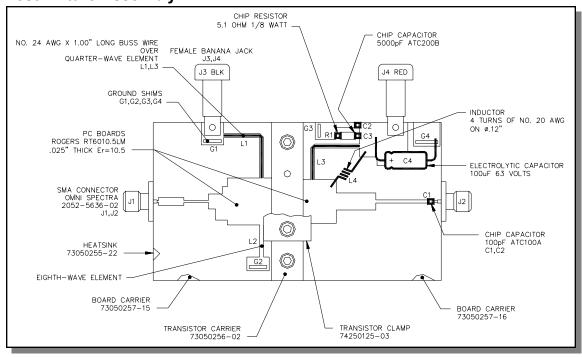
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#### **Test Fixture Circuit Dimensions**



#### **Test Fixture Assembly**



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